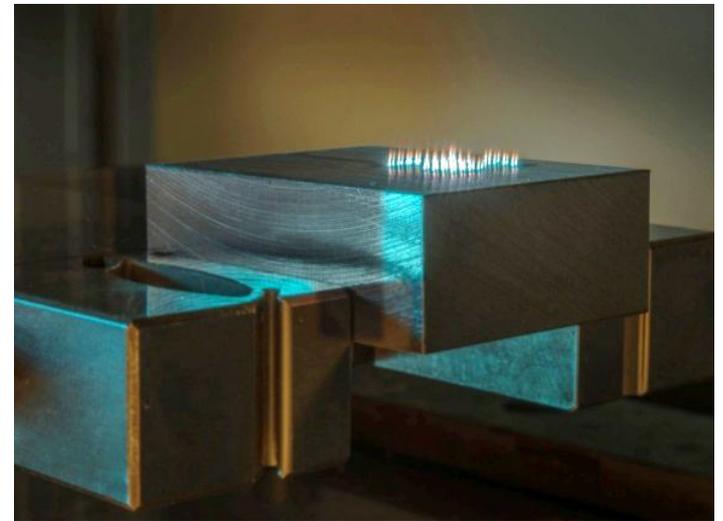
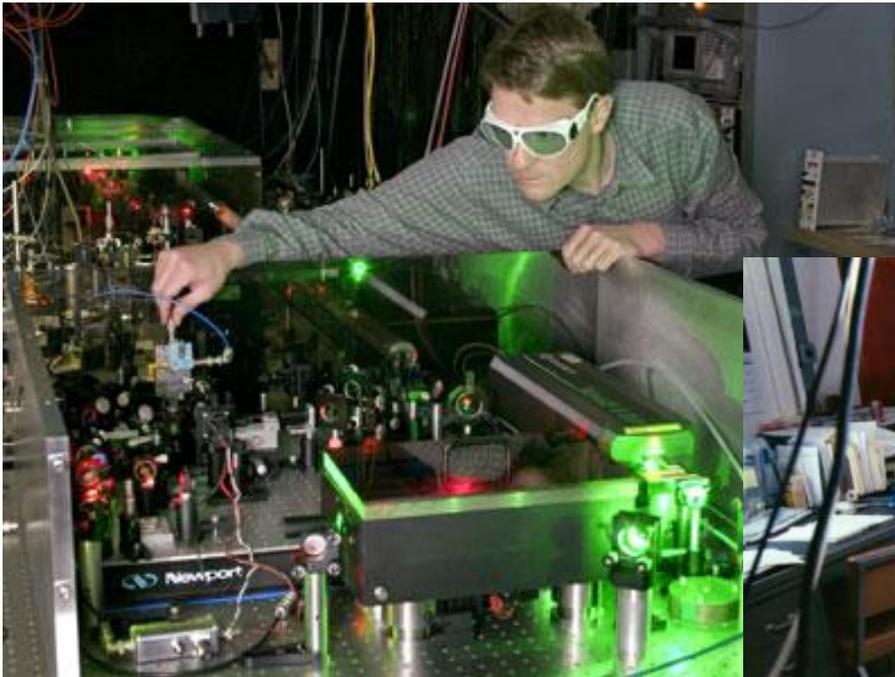

Verfahrens- und Systemtechnik zum präzisen Hochleistungsabtrag mit UKP-Lasern

Jens Holtkamp

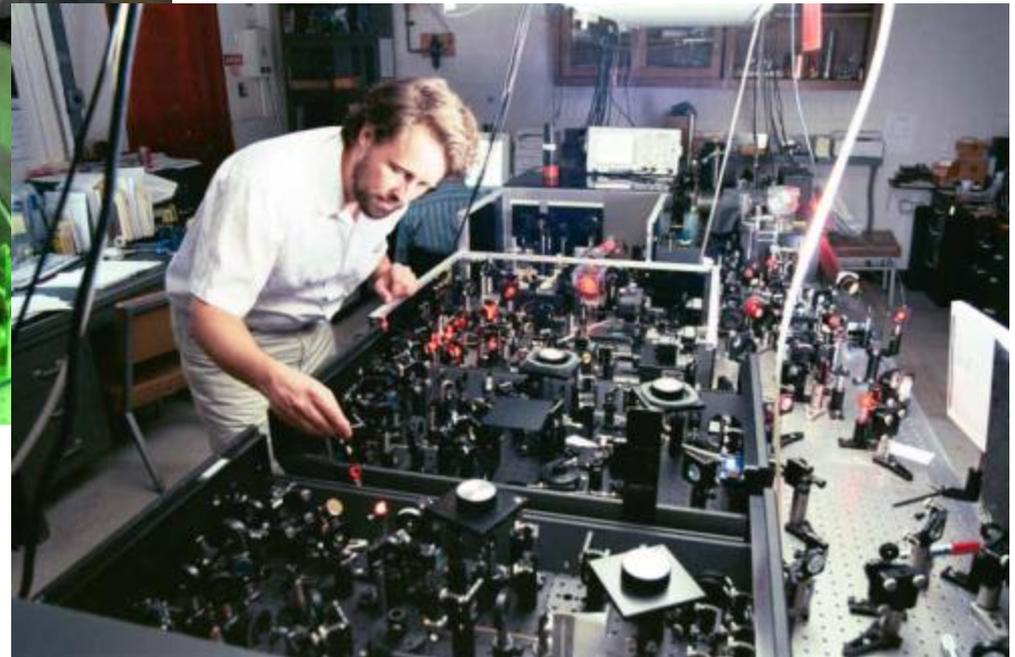


Motivation

Ultra short pulsed lasers



National Institute of Standards and Technology (NIST)



Regional Laser and Biomedical Technology Laboratories (RLBL) at the University of Pennsylvania

Motivation

High Power Ultra-short pulse laser sources

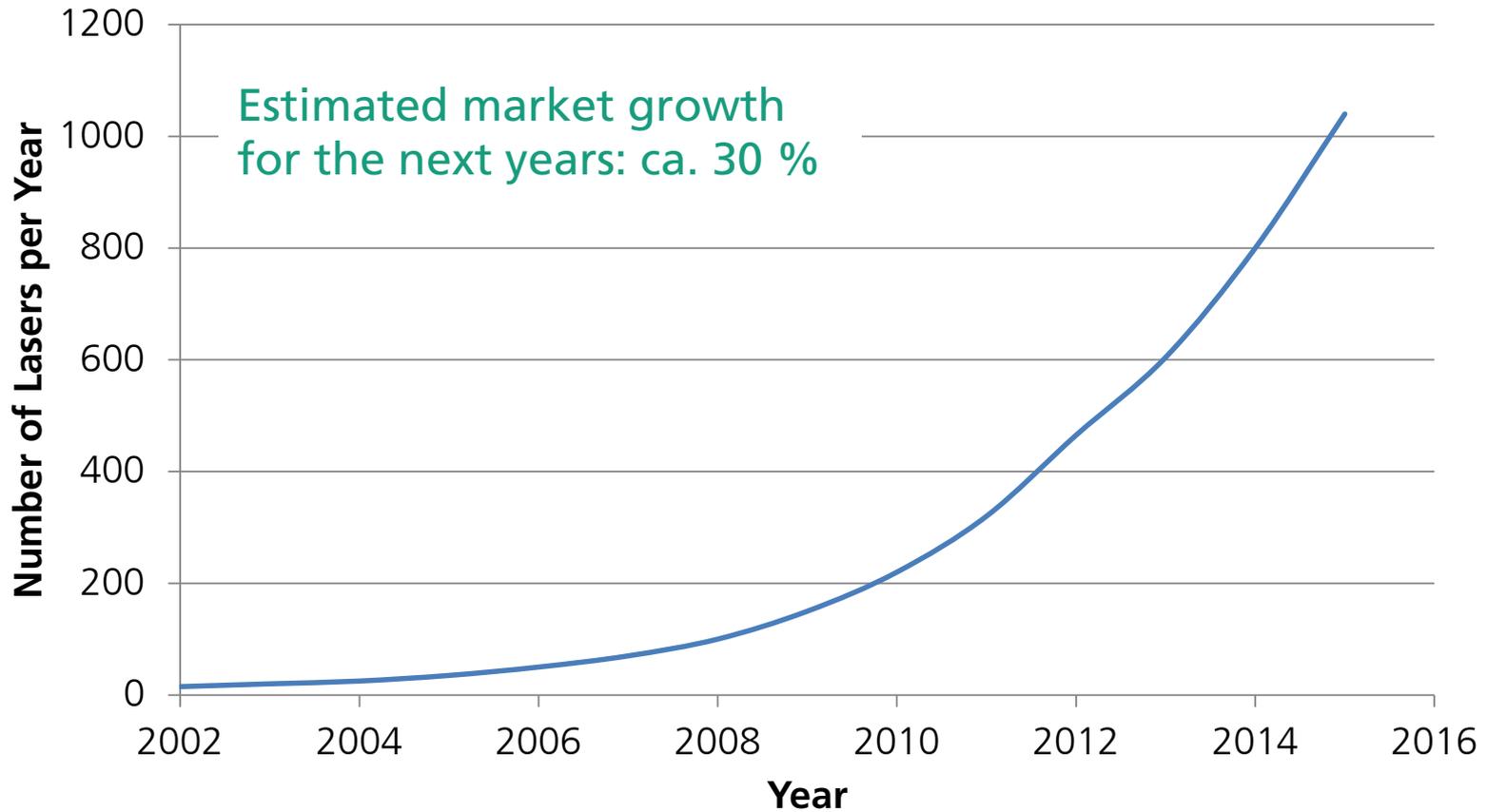


TRUMPF



Motivation

Number of ultrashort-pulsed Lasers for Material Processing

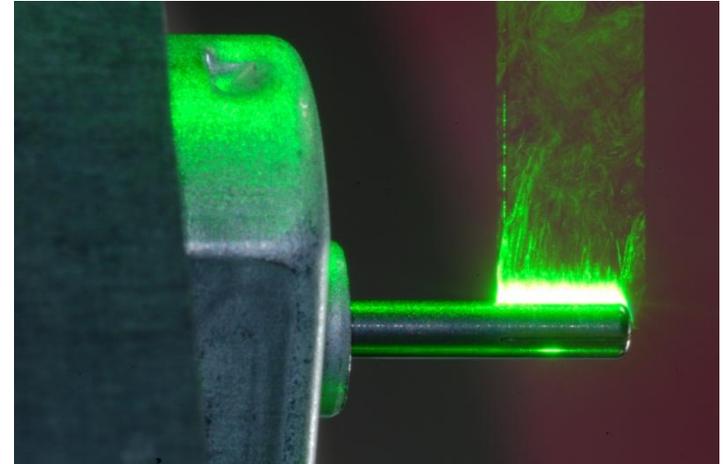


market estimation by Fraunhofer ILT

Motivation

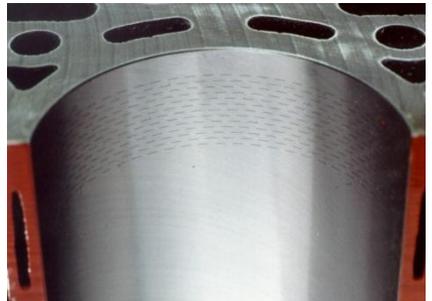
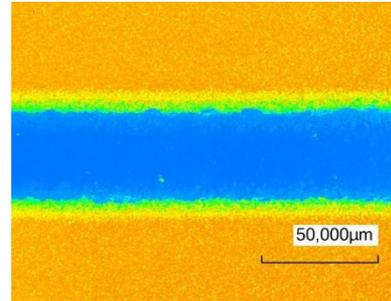
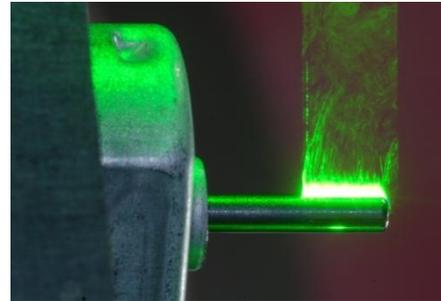
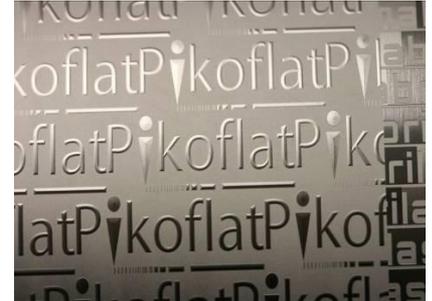
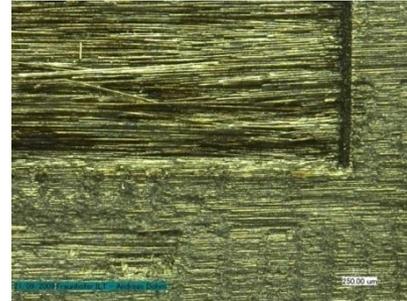
Potential of ultrashort-pulsed Lasers

- Substitution of existing Technologies
e.g. Etching, Erosion, Cutting
- Development of new Technologies e.g.
Thin film ablation,
Surface functionalisation
- Advantages of ultrashort-pulsed Lasers
 - (quasi) Material independent
 - (quasi) no thermal influence
 - Tool-free, wear-free and resource-efficient
 - Almost no lead-time (Digital Photonic Production)
 - Highest precision (lateral and vertical)
 - Universal application (due to high variety of parameters)



Motivation

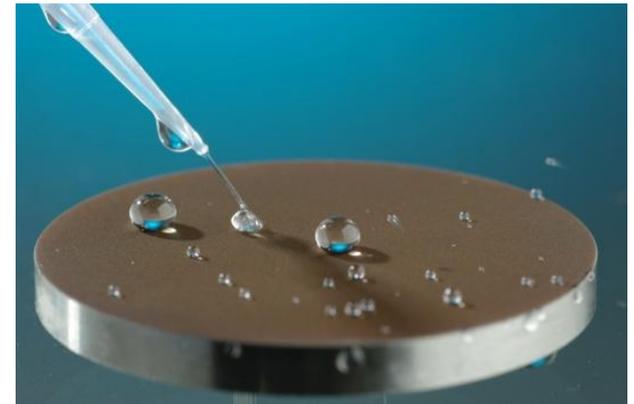
Areas of Application



Motivation

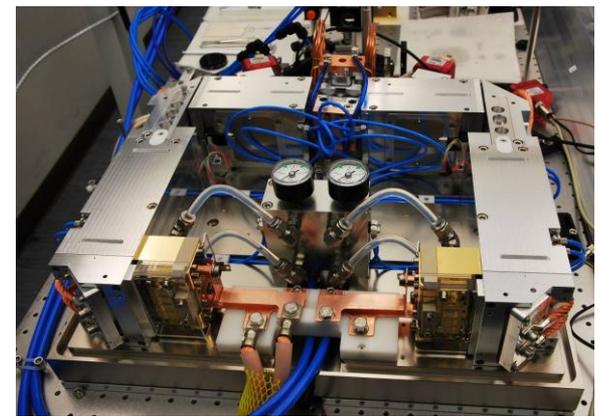
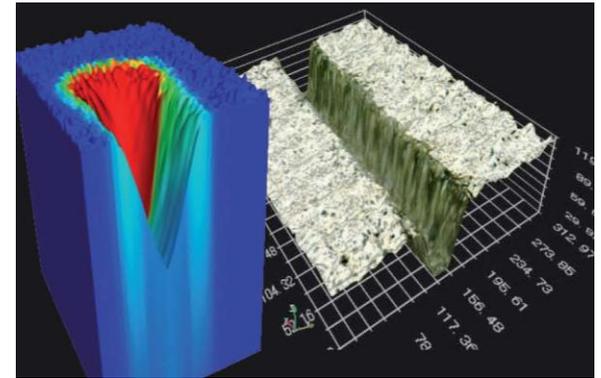
Megatrends – Areas of Application

- **Display / Light**
 - (Thin-)Glass cutting
 - Thin film ablation
 - Mask production for coating technologies
- **Energy**
 - Photovoltaik: Texturing, Drilling, Doping
 - Wind: Surface structuring of rotor blades
- **Lightweight construction**
 - Cutting and Repair of Fiber reinforced plastics
- **Resource efficiency**
 - Functional surfaces (Wetting, Tribology)
 - Light guidance
 - Wafer Dicing
- **Environment**
 - Filter for Water treatment



Tailored Light at Fraunhofer ILT

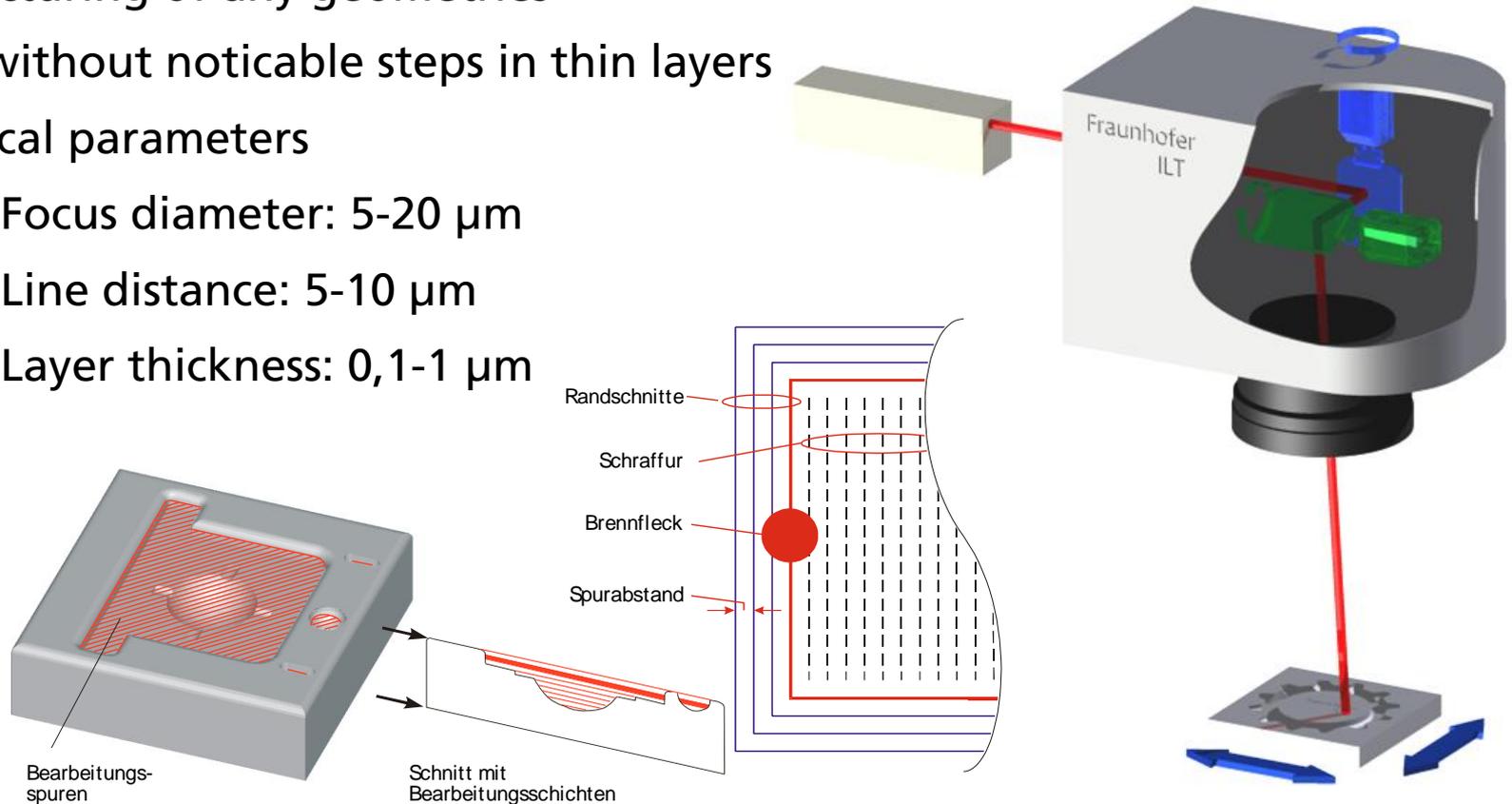
- Simulation
 - Interaction of laser radiation with material
 - Simulation of ablation processes
 - Development of ablation tools
- System Technology
 - New high power ps and fs Laser
 - Special Optics
 - Machine Technology
 - Deflection Systems
 - Process monitoring
- Process development
 - Use of different kind of laser systems and optics
 - Development of ablation strategies
 - Small batch production and Industrial validation



Basics

Process concept for laser micro ablation

- Structuring of any geometries
- 3D without noticeable steps in thin layers
- Typical parameters
 - Focus diameter: 5-20 μm
 - Line distance: 5-10 μm
 - Layer thickness: 0,1-1 μm



Basics

Process concept for laser micro ablation

- Average Power: up to 1 kW (Fa. Amphos)
- Repetition Rate: kHz...MHz (typ. 500 kHz)
- Pulse Energy: $\mu\text{J} \dots \text{mJ}$ (typ. $< 10 \mu\text{J}$)
- Pulse Power: 100 MW
- Intensity: $100 \text{ TW}/\text{cm}^2 = 10^{14} \text{ W}/\text{cm}^2 @ (10 \mu\text{m})^2$
- Ablation Rate: up to $20 \text{ mm}^3/\text{min}$ (typ. $< 5 \text{ mm}^3/\text{min}$)
- Wavelength 266 nm - 1064 nm

Basics

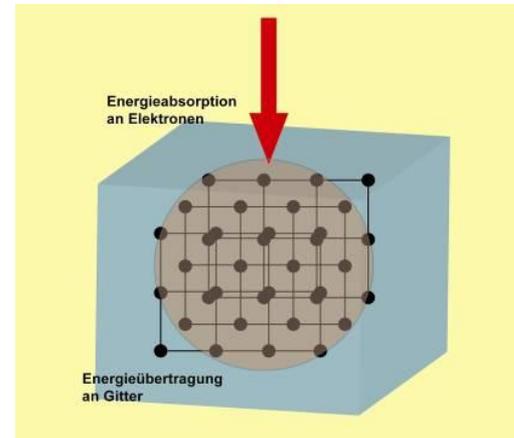
Ultra short laser pulse interaction with metals

Time Ranges of Energy Transfer

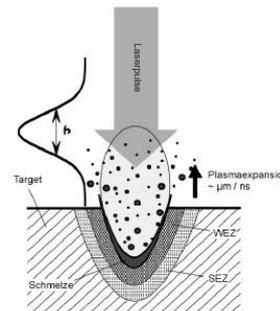
- Photon – Electron: <10 fs
- Electron – Electron: <100 fs
- Electron – Lattice: 1-10 ps
- Lattice – Lattice: speed of sound



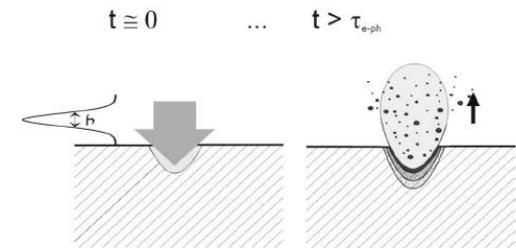
- No interaction of radiation with vapour and melt (Heating after end of laser pulse)
- Ablation mainly by vapourisation
- Minimal thermal influence



(a) ns-Ablation: $\tau \gg \tau_{e-ph}$



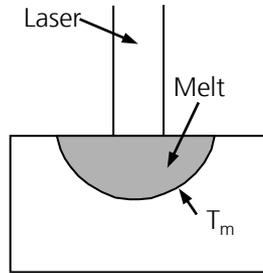
(b) fs-Ablation: $\tau \ll \tau_{e-ph}$



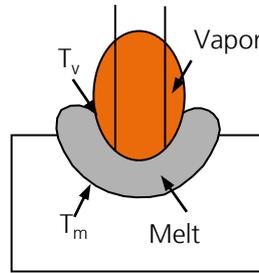
Basics

Ultra short laser pulse interaction with metals

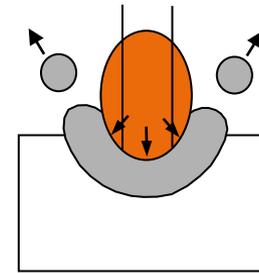
Melt dominated



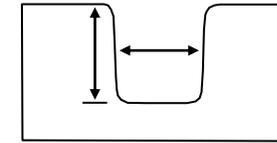
Heating



Vaporization

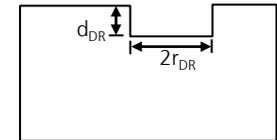
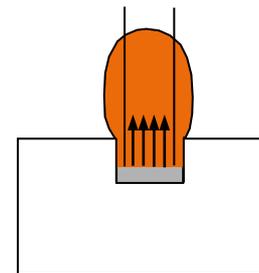
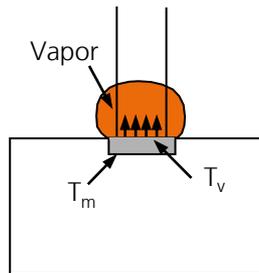
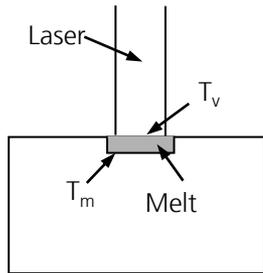


Expulsion



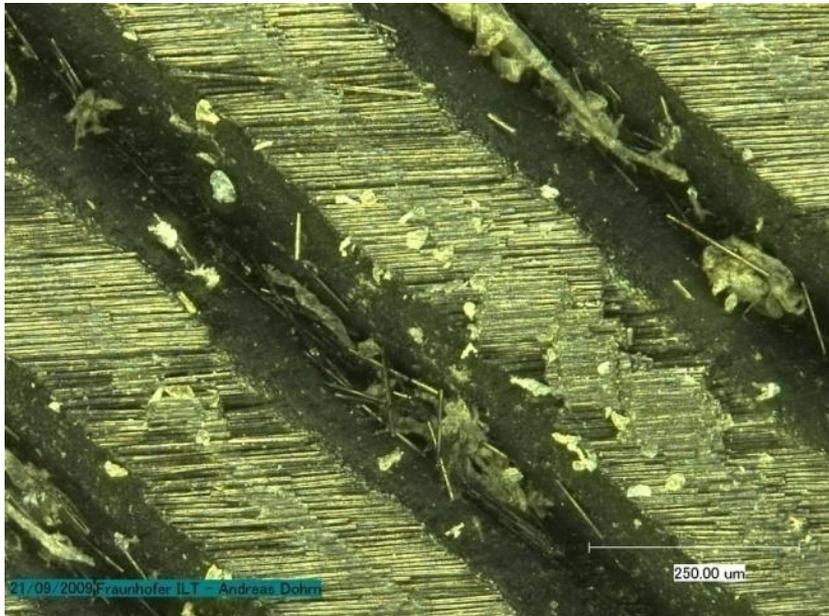
Result

Vapor dominated

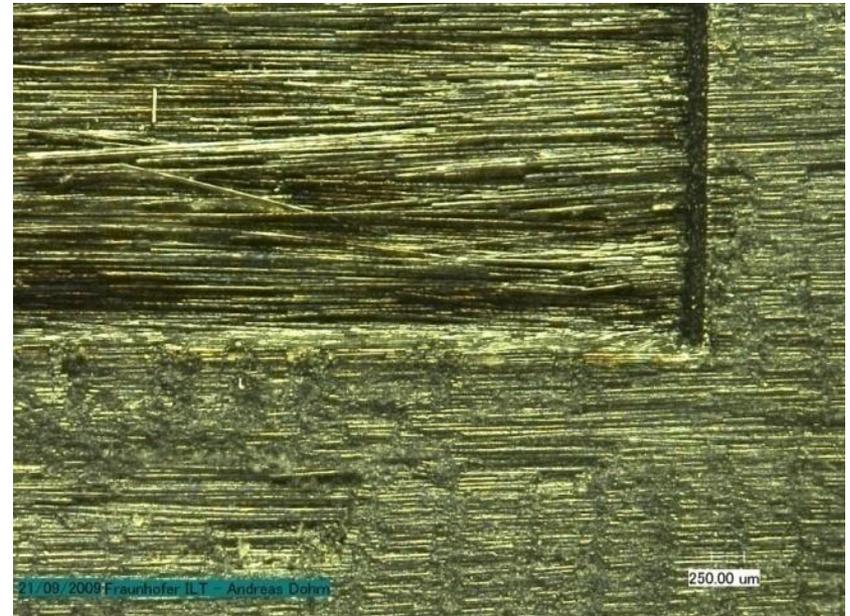


Basics

Multipass-Ablation of Composite Materials



$t_{\text{Pulse}} = 100 \text{ ns}$
Rep.-rate: 100 kHz
Pulse energy: $50 \mu\text{J}$
 $V_{\text{Scan}}: 1 \text{ m/s}$
Layer Thickness: $20 \mu\text{m}$

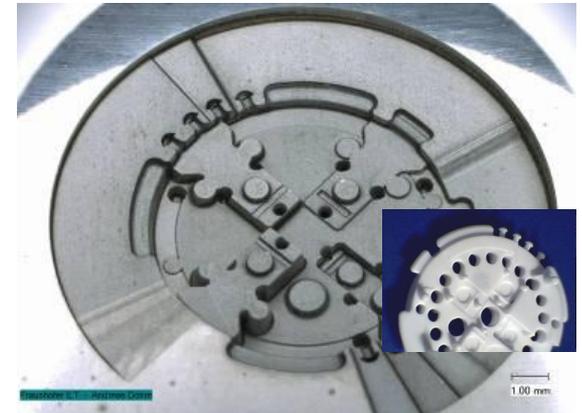


$t_{\text{Pulse}} = 10 \text{ ps}$
Rep.-rate: 100 kHz
Pulse Energy: $30 \mu\text{J}$
 $V_{\text{Scan}}: 1 \text{ m/s}$
Layer Thickness: $10 \mu\text{m}$

Basics

Laser Ablation with (Ultra-)short pulse Laser

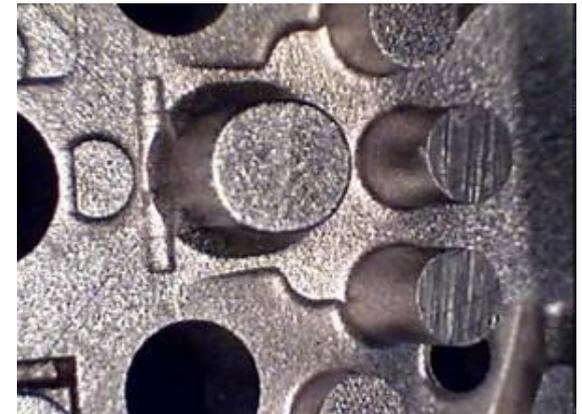
- Time for manufacturing 10 hours
- Ablated volume 100 mm³
- Quality of ablation comparable to EDM
- No tools needed



ns-Laser



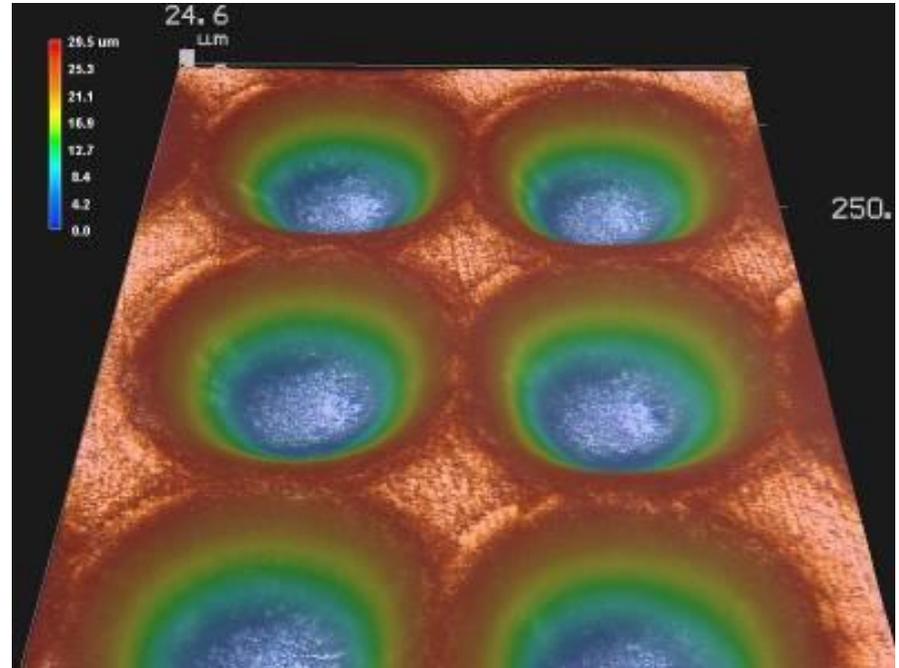
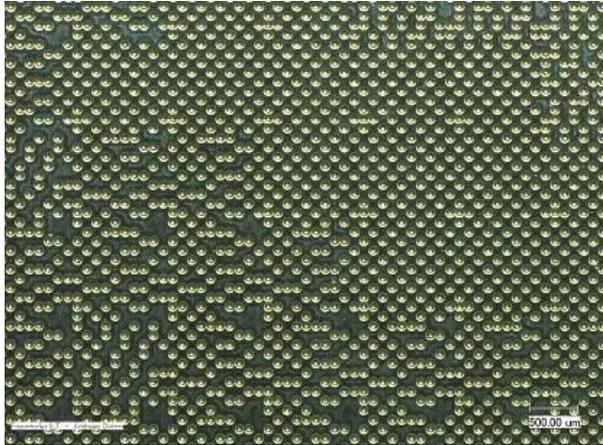
ps-Laser



Eroded

Functional Surfaces

Micro injection moulding of lens arrays with ps-Laser



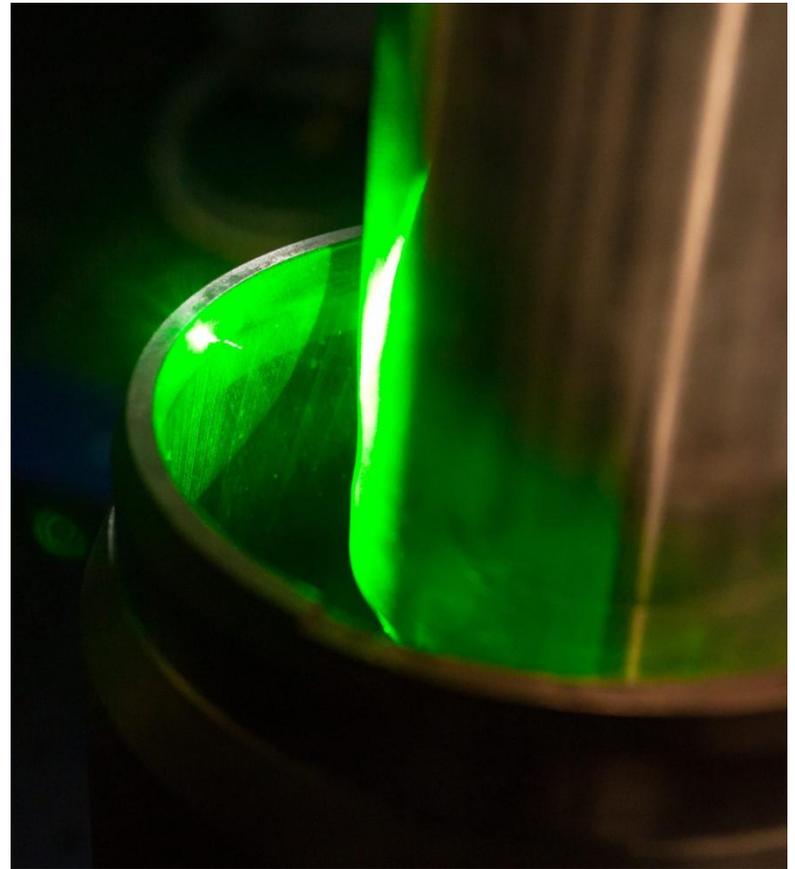
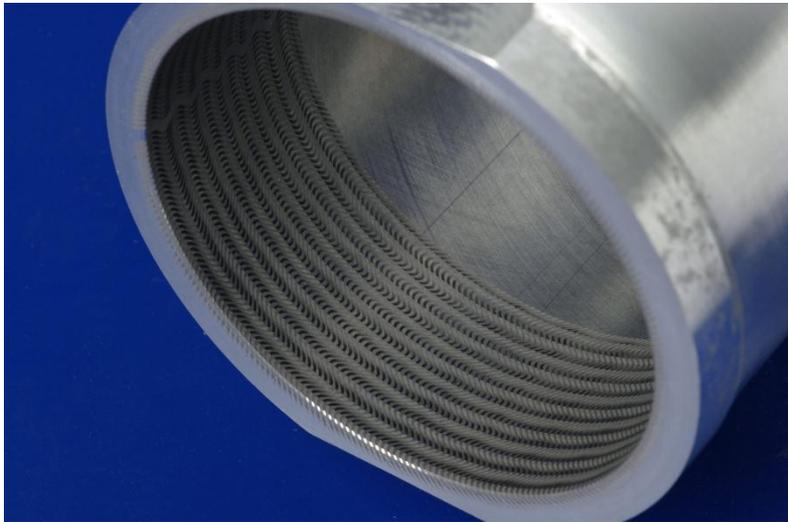
Surface quality

- After Laser ablation: $R_a = 300\text{nm}$
- After Laser polishing: $R_a = 100\text{nm}$

Functional Surfaces

Laser Structuring of Motor Components

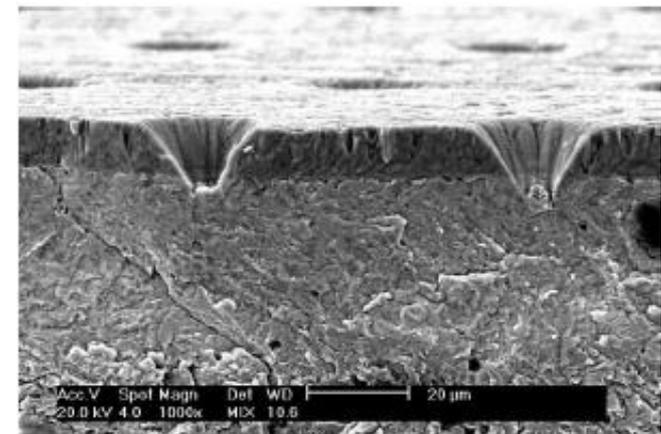
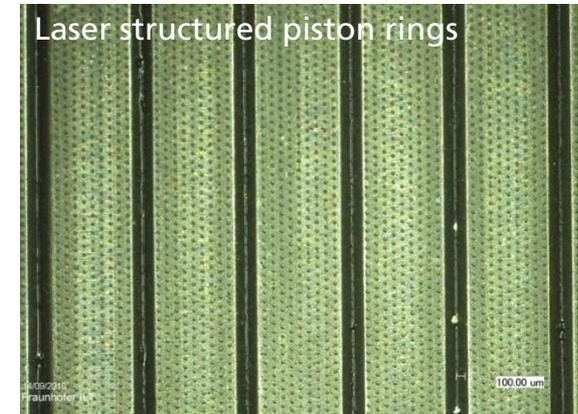
- Aim: reduction of friction and wear
- Structures act as oil reservoir and a hydrodynamic bearing
- Compromise between efficiency and oil consumption



Functional Surfaces

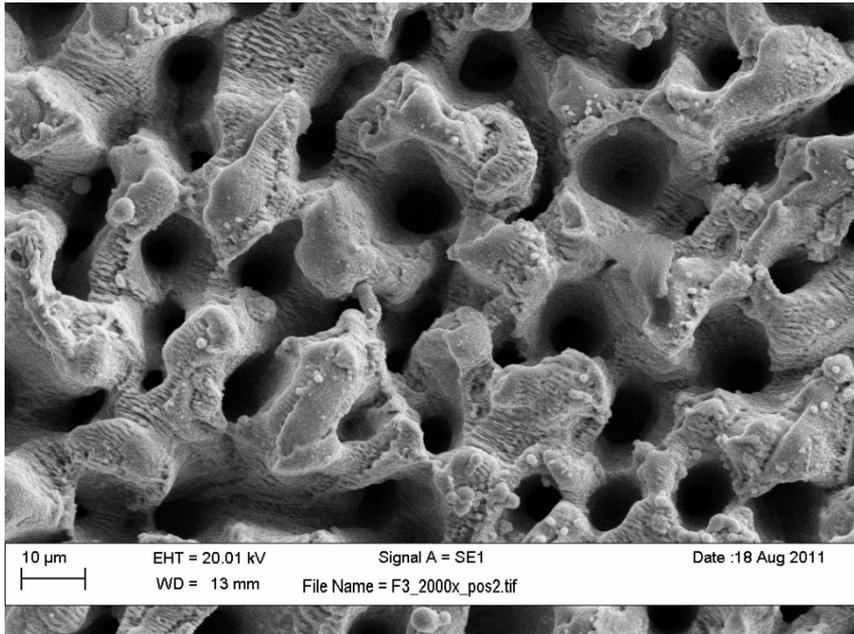
Laser Structuring of Motor Components

- Inserting of micro structures by ps laser ablation
 - No further treatment necessary
 - No thermal degradation of the adjoined material
- Applications in automotive industry under development
 - Piston rings
 - Cylinders
 - Sealing rings
 - Piston pumps



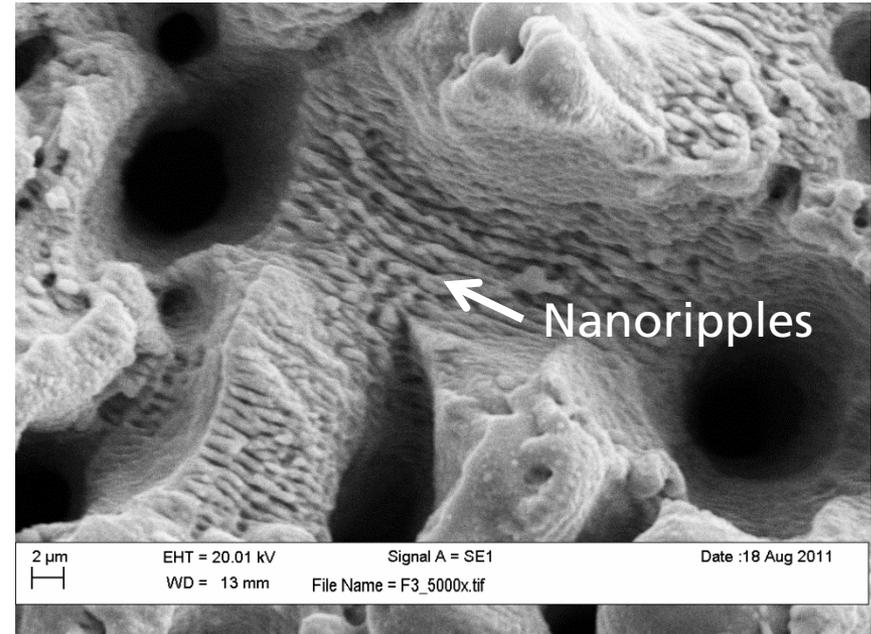
Functional Surfaces

Surface roughening



Cone-like-protrusions (CLPs)

- Statistical structure effect that occurs by redistribution of melt during ablation with ultrashort laser pulses
- Structure sizes: 6-10 μm



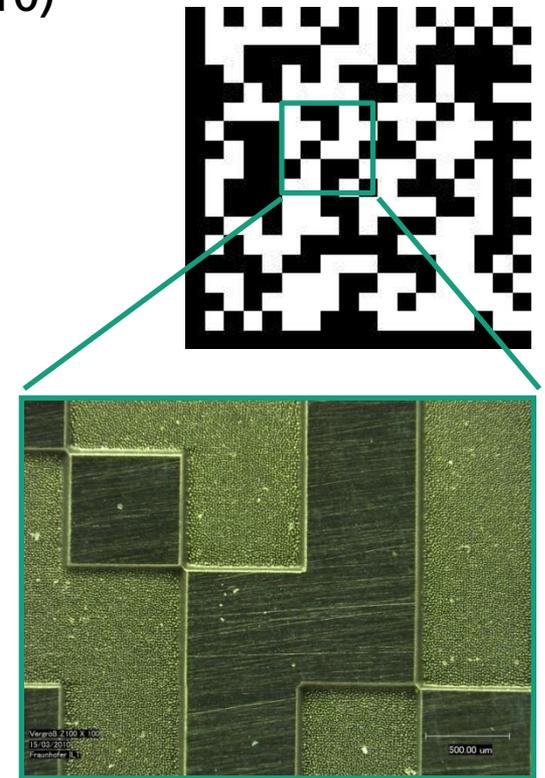
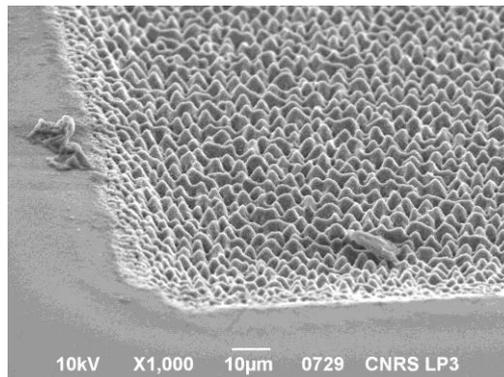
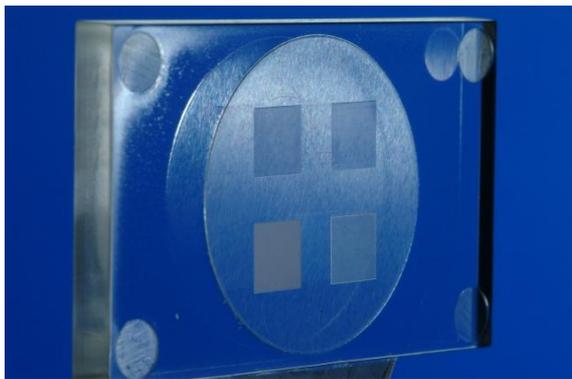
Nano ripples

- Overlay of nanostructures
- Structure size: ~1 μm

Functional Surfaces

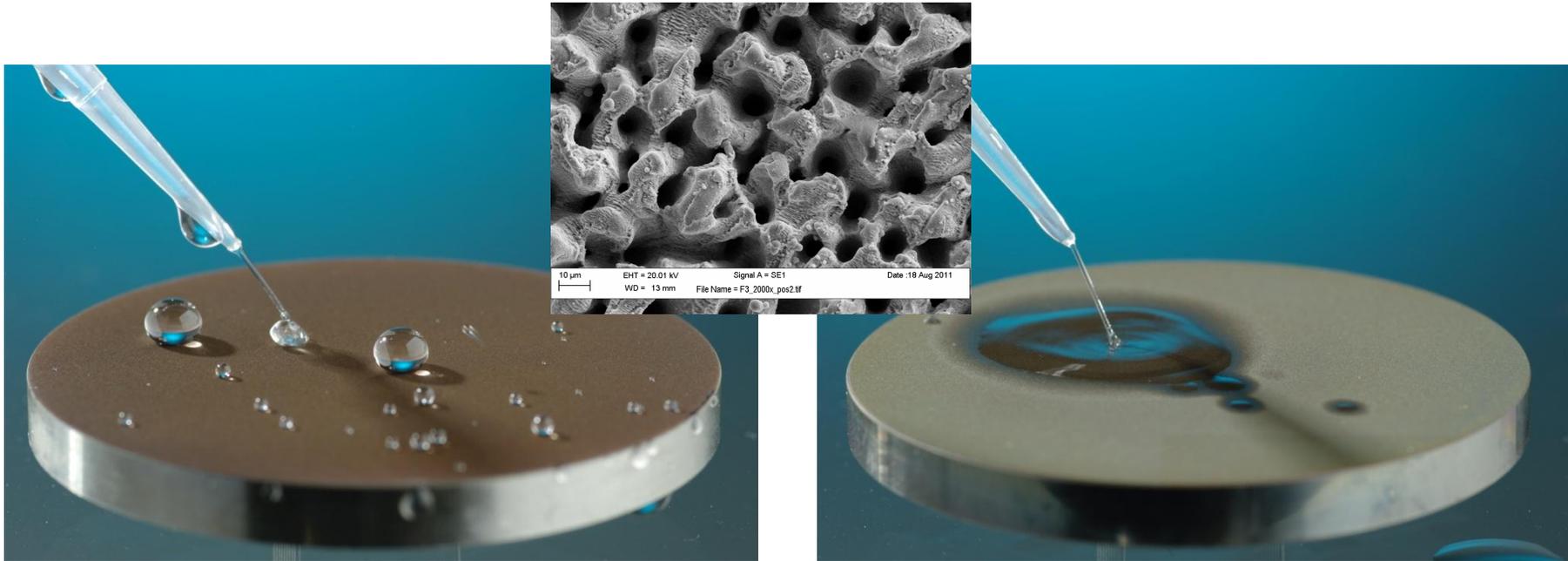
Surface roughening

- ablation of 10-30 layers with high laser intensity
- generation of structures with high aspect ratio (>10)
- Applications
 - anti-reflection surface
 - scattering area
 - Change of wetting behaviour



Functional Surfaces

CLPs - Extreme enhancement of the surface area



Hydrophobic coating

- CLP (6-7 μm)
- HMDSO Plasma Coating (300nm)
- Contact angle $> 150^\circ$

Hydrophilic coating

- CLP (6-7 μm)
- HMDSO Plasma Coating with oxygen (300nm)

Functional Surfaces

Thin film processing

■ Requirements for large area electronics:

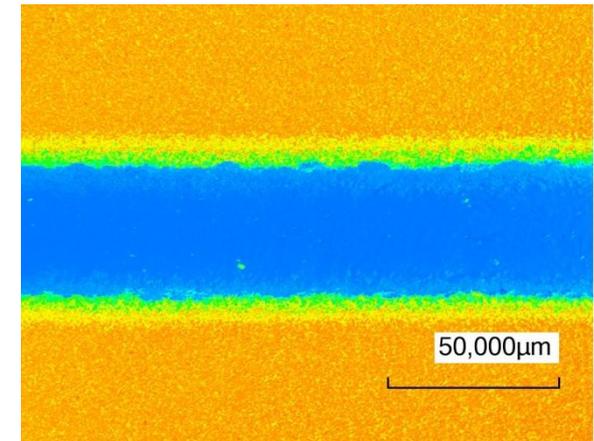
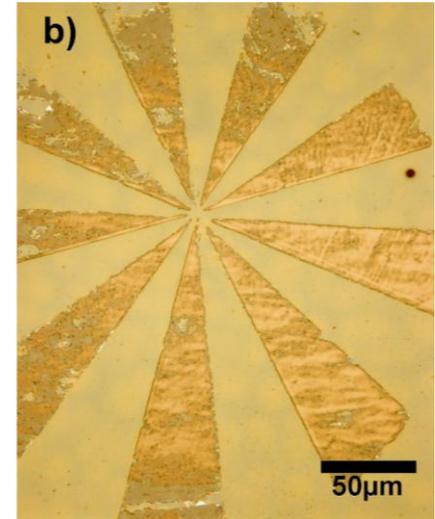
- Fast, High resolution
- Shape independent
- Different kind of layer materials and thicknesses (organic and anorganic)
- No damage of the substrate
- No delamination

■ Used Laser

- Excimer
(193 nm, 248 nm, ns, mask projection)
- Ultrafast laser
(355, 532, 1064, fs...ps, Scanner deflection)

■ Applications

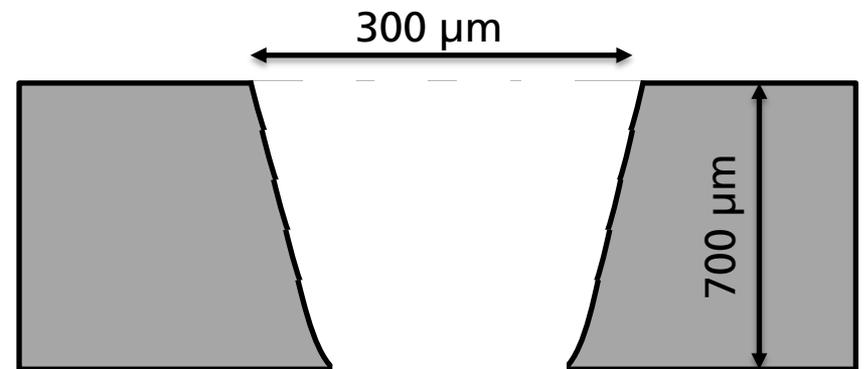
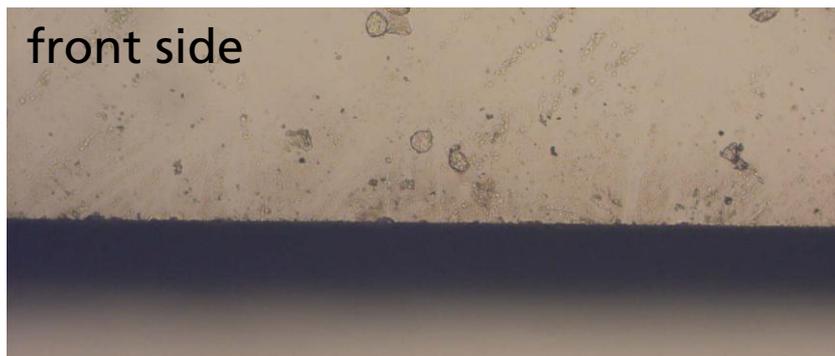
- OLED Lighting and Display
- Thin film PV



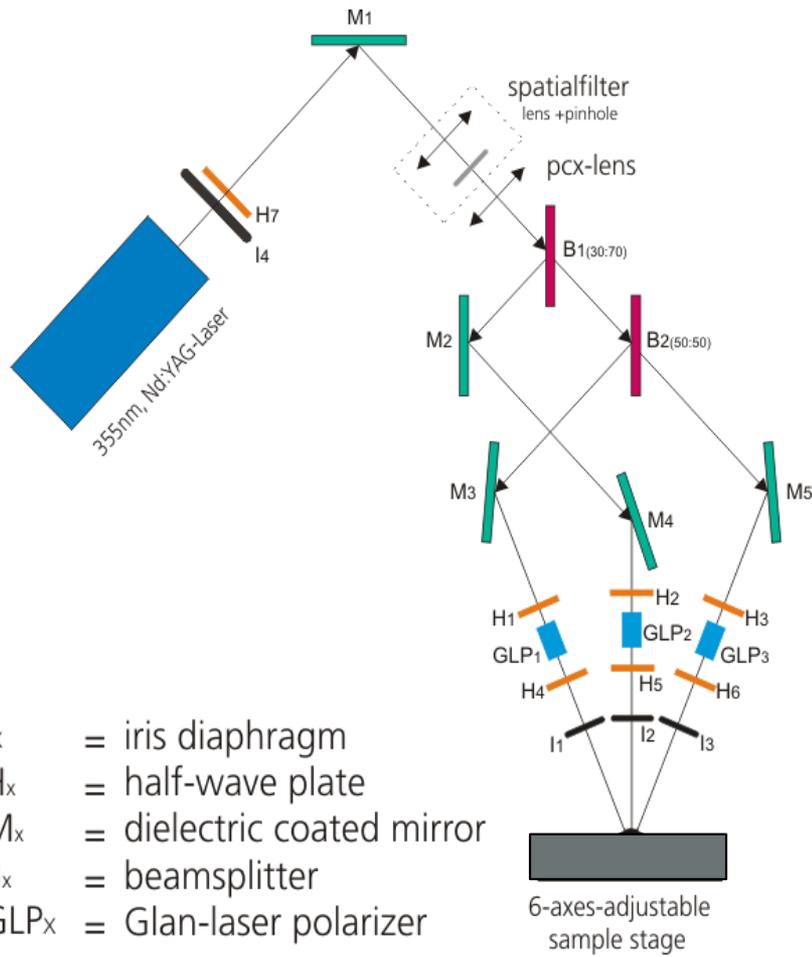
Cutting

Thin glass processing

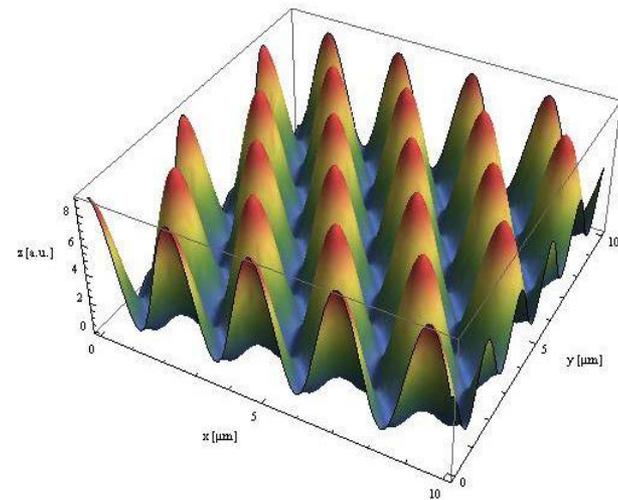
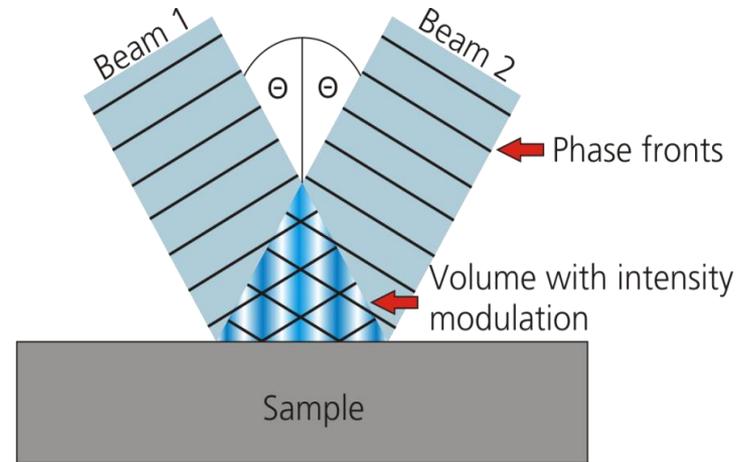
- Cutting by ablation
- Pulse duration 10 ps
- Wavelength 532 nm
- Average Power 20 W
- Number of layers 100
- Scan speed 2 – 4 m/s



Periodic Nano Structuring Interference Technique



- I_x = iris diaphragm
- H_x = half-wave plate
- M_x = dielectric coated mirror
- B_x = beamsplitter
- GLP_x = Glan-laser polarizer



Periodic Nano Structuring Interference Technique

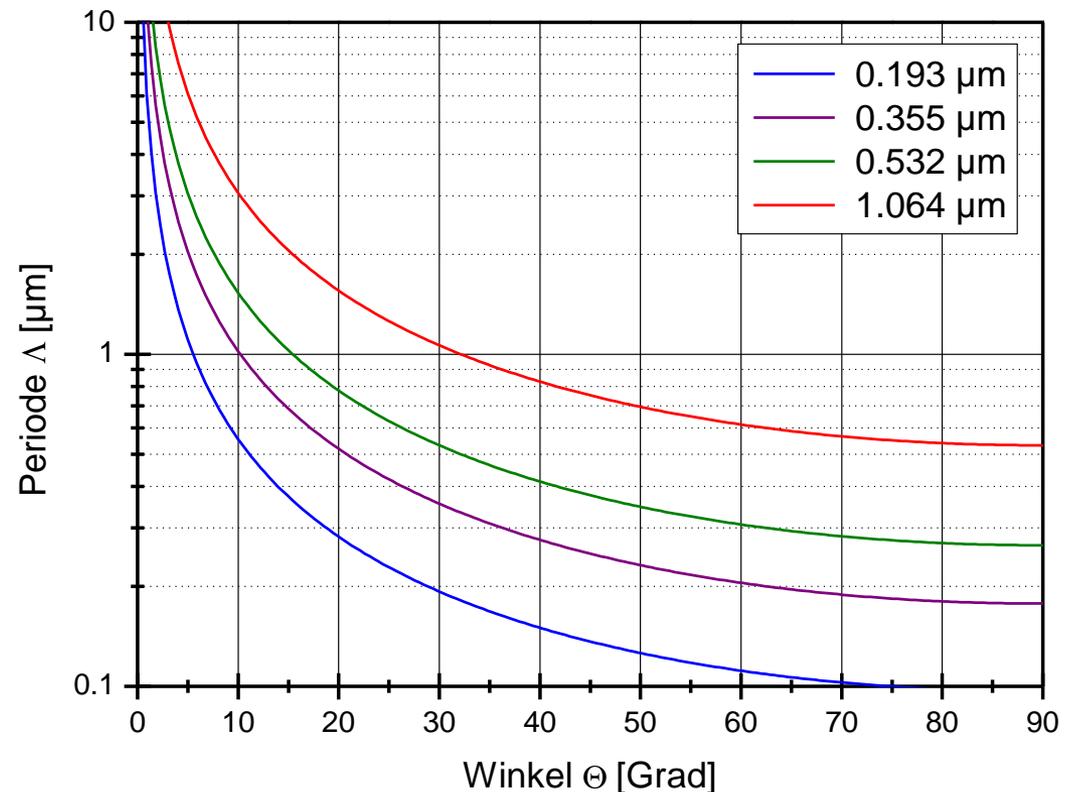
Periodicity controlled by:

- Laser wavelength
- Beam configuration
- Intersection angle

Formula:

$$\Lambda_{\text{periode}} = \frac{\lambda_{\text{Laser}}}{2 \sin \Theta_{\text{VW}}}$$

Factor depends on
beam configuration



Periodic Nano Structuring Interference Technique

Potential

- Structures sizes: 100 nm - 5000 nm
- High uniformity of the created structures
- Whole beam diameter is structured simultaneously
- Non-flat surfaces can be processed
- Nearly material independent
- Only one process step

Challenges

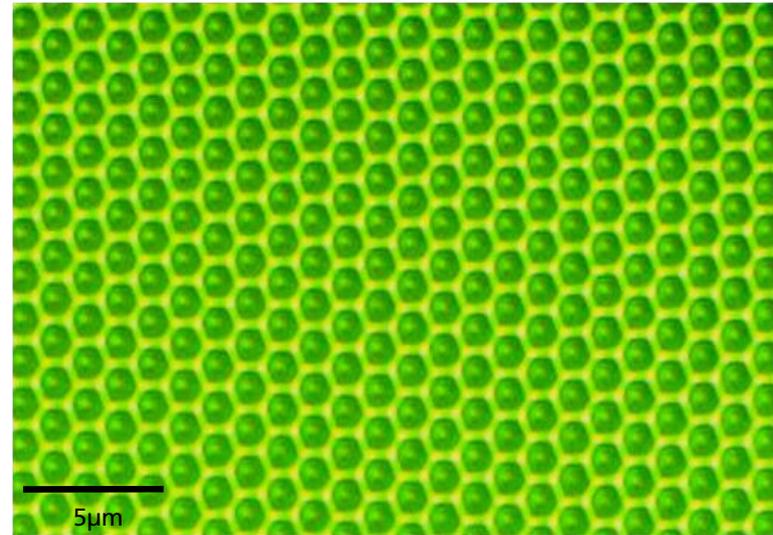
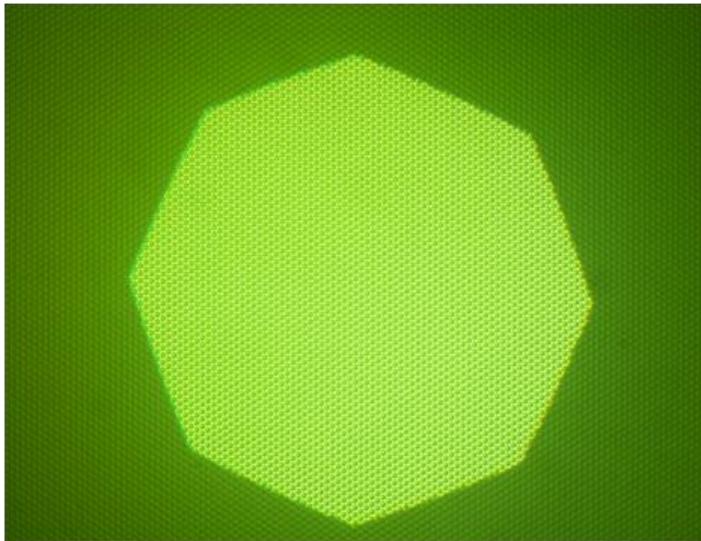
- Gaussian beam profile leads to variations in structure size and depth over a spot
- Stitching necessary to structure area larger than the spot diameter
- Laboratory stage



Periodic Nano Structuring

Multi-Beam-Interference

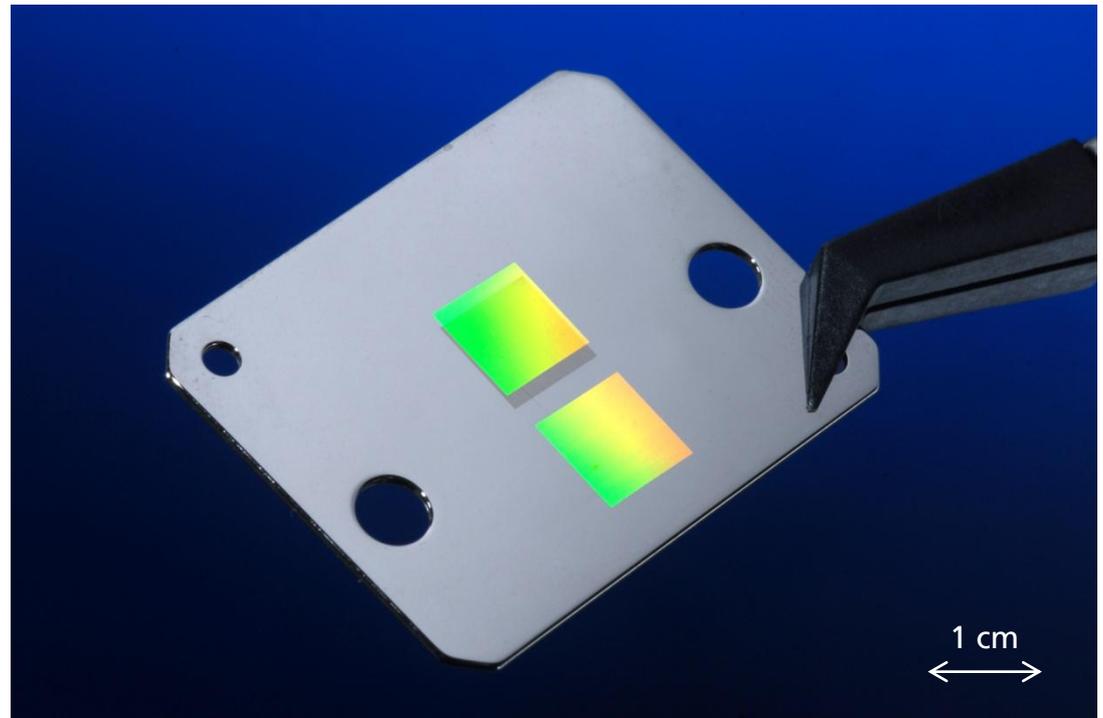
- Structure geometry: $\text{Ø}1 \mu\text{m}$; depth: 600 nm
- Material: PEEK
- 100.000 holes with one shot
- Homogeneous structures over the entire spot ($\text{Ø}500 \mu\text{m}$)



Periodic Nano Structuring

Multi-Beam-Interference

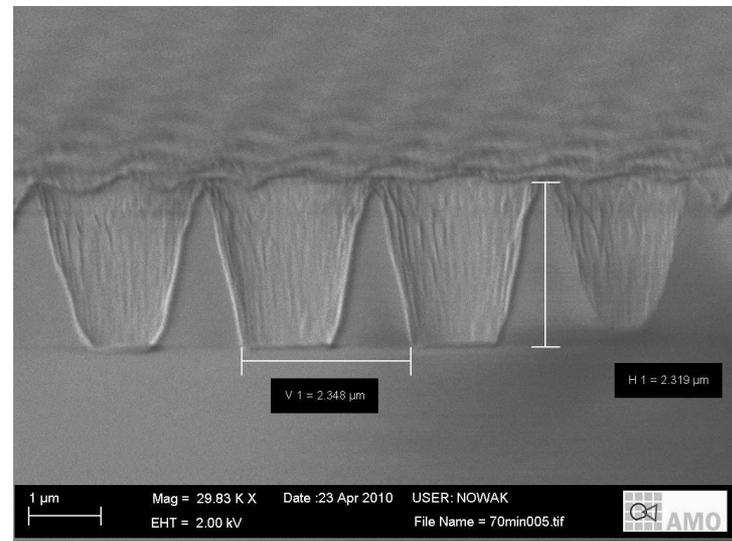
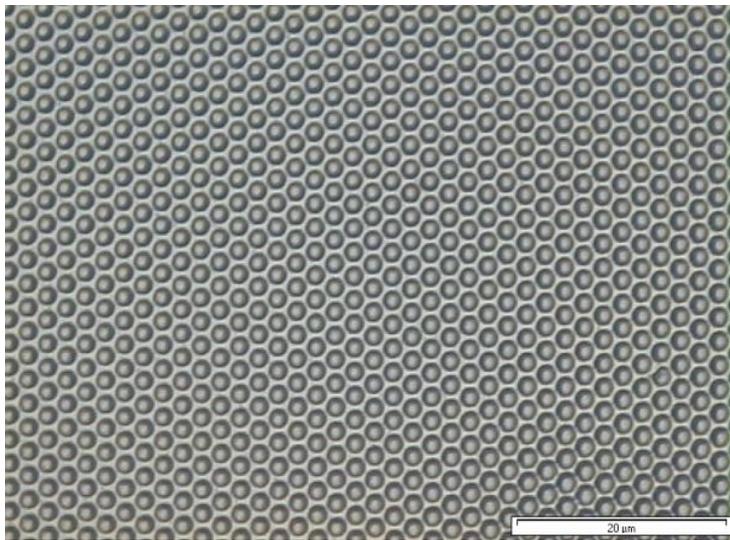
- Material: Stainless Steel
- Periodicity: 530 nm
- Focal diameter: 60 μm
- Wavelength: 355 nm
- 10 ps pulse duration



Periodic Nano Structuring

Multi-Beam-Interference

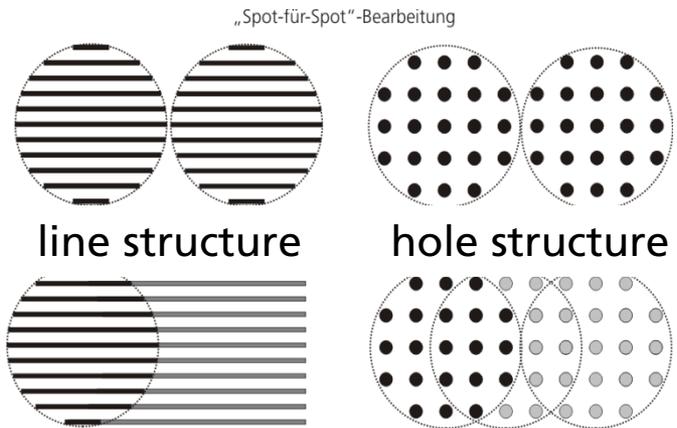
- Structure geometry: $\varnothing 1,6 \mu\text{m}$; Depth: $2,3 \mu\text{m}$
- Material: Quartz glass
- Structuring into Photoresist
- Subsequent Reactiv Ion Etching



Periodic Nano Structuring Interference Technique

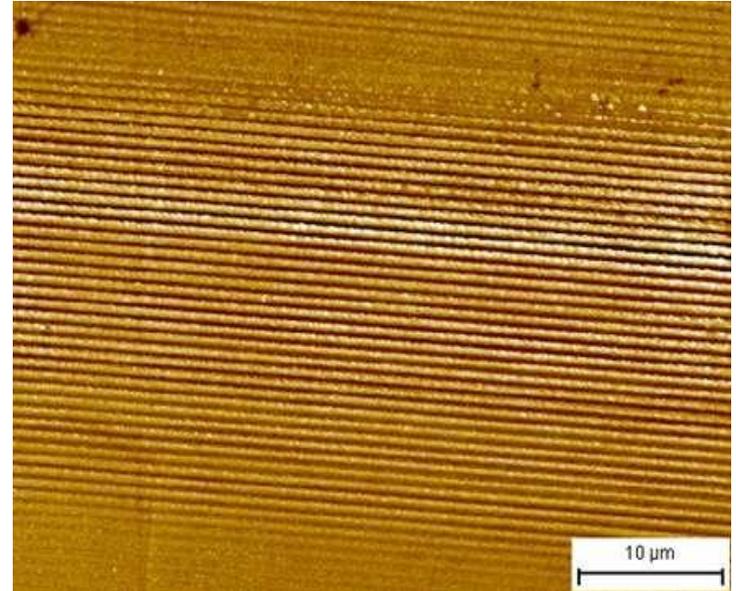
Parameter

- Laser: 355nm, 400kHz, 10 ps
- Material: Brass
- Spot size: 30 – 50 μm
- Feed rate: 4500 mm/min
- Periodicity: 780 nm



Spot
by
spot

pulse
overlap



Bearbeitung mit einem Pulsüberlappansatz

Future Developments

High Precision at Large Components



Cutting of fiber reinforced polymers



Large area processing



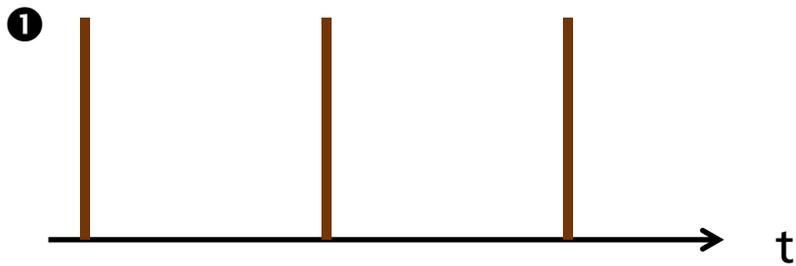
Surface structuring



Low friction surfaces

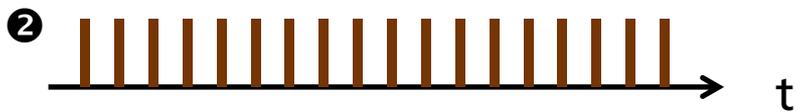
Large area processing

System strategies



high pulse energy / low replate?

or



high replate / low pulse energy?

Large area processing

Polygonic Mirror

- Max. Scan velocity: 340 m/s
(max. rpm: 12.000)
- Focal distance: 163 mm
- Focal diameter: 20-25 μm
- Scan-field: 100x100 mm²
- Data import: Bitmap, PNG, 2D Array
(Gray-scale value corresponds to number of Layers)
- Additional linear motor
- Number of mirrors: 11
- Max. Output Frequency:
modulated 20 MHz; digital 40 MHz

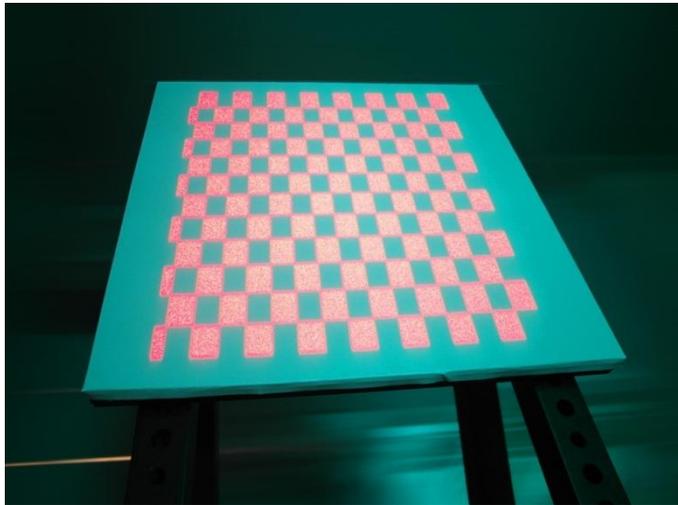


Large area processing

Polygonic Mirror

Chess pattern

- Calculation on FPGA
- 40 MHz Output Frequency
- Feed rate: 35 mm/s
- 9500 rpm



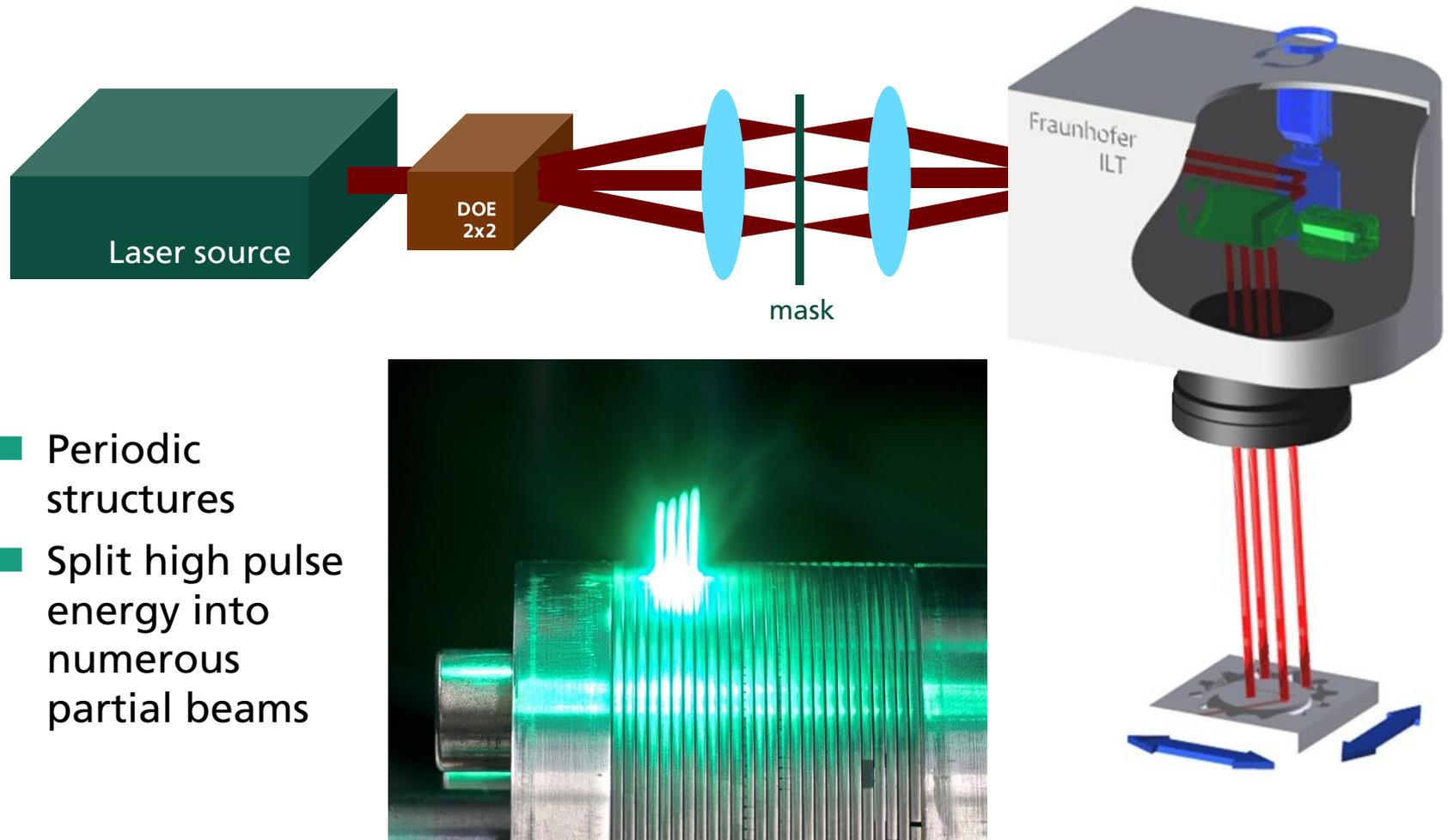
AC Dom, ILT + Polyscan Logo

- PNG-Import (25 MPix)
- 10 MHz Output Frequency
- Feed rate: 18 mm/s
- 2800 rpm



Large area processing

Multi-beam laser processing with DOEs



Large area processing

Micro structured Embossing rolls

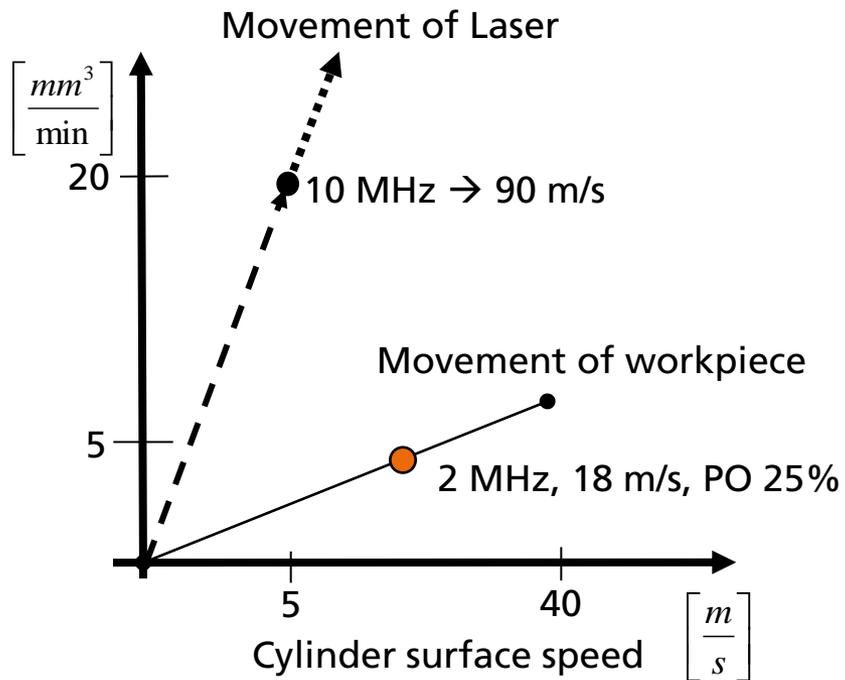
- Material: chrome-plated Copper
 - Dimensions:
Ø250 mm; length 1 m
 - Rotational speed:
1400 rpm ($v = 15$ m/s)
 - Line distance: 2 μm
 - Focus diameter: 10 μm
 - Laser power: 100 W
-
- Surface roughness $< 0,5$ μm
 - Min. structure size: 5 μm
 - No burr



Large area processing

Micro structured Embossing rolls

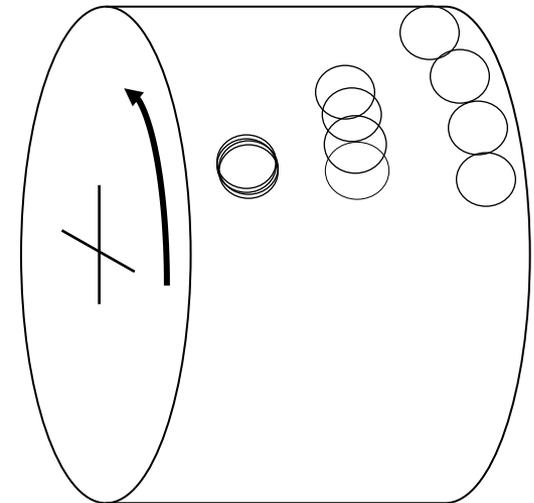
- Higher ablation rate by additional scanning device



- Pulse overlap is controlled by rotational speed (fixed rep.rate)

Surface speed 1m/s 10m/s 20m/s

Pulse overlap 90% 50% 0%
(@ 2 MHz)



Future Developments

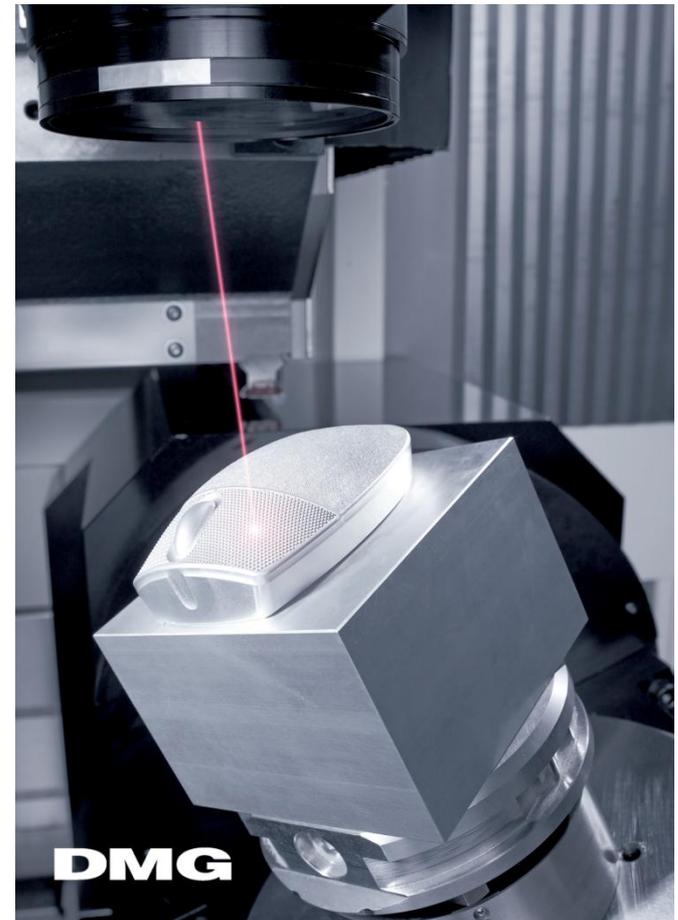
Ultrafast Manufacturing

Today:

- Typical ablation rates of e.g. Aluminum ca. $1 \text{ mm}^3/\text{min}$
- Limited by max. Laser power and Scanning speed

Future potential:

- Ablation rates of $>5 \text{ mm}^3/\text{sec}$
- Use of fast deflection systems and $>1 \text{ kW}$ average Power
- Direct manufacturing of small components e.g. with specific surface features



SAVE THE DATE

2. AACHENER ULTRAKURZPULSLASER-WORKSHOP

17./18. APRIL 2013

